# **Monolithic Amplifier**

DC-6 GHz

#### **Product Features**

- DC-6 GHz
- Single Voltage Supply
- Internally Matched to 50 Ohms
- Unconditionally Stable
- Low Performance Variation Over Temperature
- Transient Protected
- Aqueous washable
- Protected By US Patent 6,943,629

## **Typical Applications**

- Cellular/ PCS/ 3G Base Station
- CATV, Cable Modem & DBS
- Fixed Wireless & WLAN
- Microwave Radio & Test Equipment



CASE STYLE: WW107 PRICE: \$1.57 ea. QTY. (30)

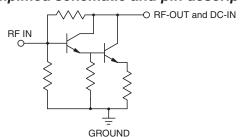
+ RoHS compliant in accordance with EU Directive (2002/95/EC)

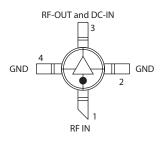
The +Suffix has been added in order to identify RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications.

## **General Description**

ERA-2SM+ (RoHS compliant) is a wideband amplifier offering high dynamic range. It has repeatable performance from lot to lot. It is enclosed in a Micro-X package. ERA-2SM+ uses Darlington configuration and is fabricated using InGaP HBT technology. Expected MTBF is 8,000 years at 85°C case temperature.

## simplified schematic and pin description





Function	Pin Number	Description
RF IN	1	RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation.
RF-OUT and DC-IN	3	RF output and bias pin. DC voltage is present on this pin; therefore a DC blocking capacitor is necessary for proper operation. An RF choke is needed to feed DC bias without loss of RF signal due to the bias connection, as shown in "Recommended Application Circuit".
GND	2,4	Connections to ground. Use via holes as shown in "Suggested Layout for PCB Design" to reduce ground path inductance for best performance.



For detailed performance specs & shopping online see web site

#### Electrical Specifications at 25°C and 40mA, unless noted

Parameter		Min.	Тур.	Max.	Units	Cpk
Frequency Range*		DC		6	GHz	
Gain	f=0.01 GHz	15.4	16.4	17.3	dB	≥ 1.5
	f=0.1 GHz	15.4	16.4	17.3		
	f=1 GHz		15.8			
	f=2 GHz	13.7	14.9	16.5		
	f=3 GHz		13.9			
	f=4 GHz	11.6	12.5	14.6		
	f=6 GHz		10.7			
Magnitude of Gain Variation versus Temperature	f=0.1 GHz		.0025	.005	dB/°C	
(values are negative)	f=1 GHz		.003	.006		
	f=2 GHz		.0035	.007		
	f=3 GHz		.0045	.009		
	f=4 GHz		.0045	.009		
	f=6 GHz		.006	.011		
Input Return Loss	f=0.1 GHz		30		dB	
•	f=3 GHz		25			
	f=6 GHz		22			
Output Return Loss	f=0.1 GHz		25		dB	
'	f=3 GHz		16			
	f=6 GHz		14			
Reverse Isolation	f=3 GHz	18	20		dB	
Output Power @ 1 dB compression	f=0.1 GHz		13.1		dBm	≥ 1.33
	f=2 GHz	11	13			
	f=4 GHz		11			
Saturated Output Power	f=0.1 GHz		14		dBm	
(at 3dB compression)	f=2 GHz		13			
	f=4 GHz		12			
Output IP3	f=0.1 GHz	25	29		dBm	≥ 1.33
	f=2 GHz	25	29			
	f=4 GHz	20	25			
Noise Figure	f=0.1 GHz		3.2	3.7	dB	≥ 1.33
	f=2 GHz		3.3	3.8		
	f=4 GHz		3.4	4		
Group Delay	f=2 GHz		80		psec	
Recommended Device Operating Current			40		mA	
Device Operating Voltage		3.20	3.4	3.6	V	≥ 1.5
Device Voltage Variation vs. Temperature at 40mA			-2.5		mV/°C	
Device Voltage Variation vs. Current at 25°C			8.1		mV/mA	
Thermal Resistance, junction-to-case <sup>1</sup>			160		°C/W	

<sup>\*</sup>Guaranteed specification DC-6 GHz. Low frequency cut off determined by external coupling capacitors.

# **Absolute Maximum Ratings**

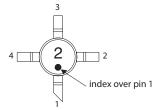
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Parameter	Ratings
Operating Temperature*	-45°C to 85°C
Storage Temperature	-65°C to 150°C
Operating Current	75mA
Power Dissipation	330mW
Input Power	15dBm

Note: Permanent damage may occur if any of these limits are exceeded. These ratings are not intended for continuous normal operation. 
¹Case is defined as ground leads.

For detailed performance specs & shopping online see web site

<sup>\*</sup>Based on typical case temperature rise 5°C above ambient.

### **Product Marking**



Markings in addition to model number designation may appear for internal quality control purposes.

#### **Additional Detailed Technical Information**

Additional information is available on our web site. To access this information enter the model number on our web site home page.

Performance data, graphs, s-parameter data set (.zip file)

Case Style: WW107

Plastic micro-x, .085 body diameter, lead finish: tin/silver/nickel

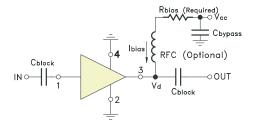
Tape & Reel: F4

Suggested Layout for PCB Design: PL-075

**Evaluation Board: TB-408-2+** 

**Environmental Ratings: ENV08T2** 

## **Recommended Application Circuit**



Test Board includes case, connectors, and components (in bold) soldered to PCB

R BIAS				
Vcc	"1%" Res. Values (ohms) for Optimum Biasing			
7	88.7			
8	113			
9	137			
10	162			
11	187			
12	213			
13	237			
14	261			
15	287			
16	309			
17	332			
18	365			
19	392			

#### **ESD Rating**

Human Body Model (HBM): Class 1A (250 v to < 500 v) in accordance with ANSI/ESD STM 5.1 - 2001

Machine Model (MM): Class M1 (< 100 v) in accordance with ANSI/ESD STM 5.2 - 1999

#### **MSL Rating**

Moisture Sensitivity: MSL1 in accordance with IPC/JEDECJ-STD-020C

No.	Test Required	Condition	Standard	Quantity
1	Visual Inspection	Low Power Microscope Magnification 40x	MIP-IN-0003 (MCT spec)	45 units
2	Electrical Test	Room Temperature	SCD (MCL spec)	45 units
3	SAM Analysis	Less than 10% growth in term of delamination	J-Std-020C (Jedec Standard)	45 units
4	Moisture Sensitivity Level 1	Bake at 125°C for 24 hours Soak at 85°C/85%RH for 168 hours Reflow 3 cycles at 260°C peak	J-Std-020C (Jedec Standard)	45 units

#### **MSL Test Flow Chart**

